TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED TYPE

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SWITCHING REGULATOR AND HIGH VOLTAGE SWITCHING APPLICATIONS.

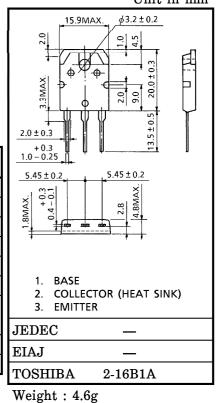
HIGH SPEED DC-DC CONVERTER APPLICATIONS.

- **Excellent Switching Times**
 - : t_r =1.0 μ s (Max.), t_f =1.0 μ s (Max.) at I_C =4A
- High Collector Breakdown Voltage: VCEO=400V

MAXIMUM RATINGS (Ta = 25°C)

CHARACT	SYMBOL	SYMBOL RATING			
Collector-Base Voltage		v_{CBO}	500	V	
Collector-Emitter Voltage		v_{CEO}	400	V	
Emitter-Base Voltage		$V_{ m EBO}$	7	V	
Collector Current	DC	$I_{\mathbf{C}}$	8	A	
	Pulse	I_{CP}	10	A	
Base Current		I_{B}	4	A	
Collector Power	Ta=25°C	Da	2.5	w	
Dissipation	$Tc = 25^{\circ}C$	PC	80		
Junction Temperature		T_{j}	150	°C	
Storage Temperature Range		$T_{ m stg}$	-55~150	°C	

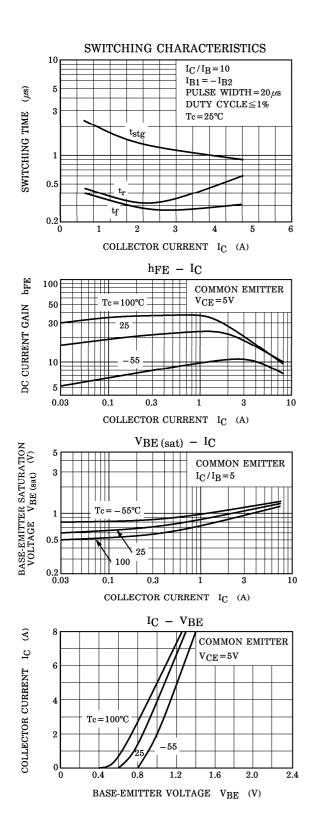
INDUSTRIAL APPLICATIONS Unit in mm

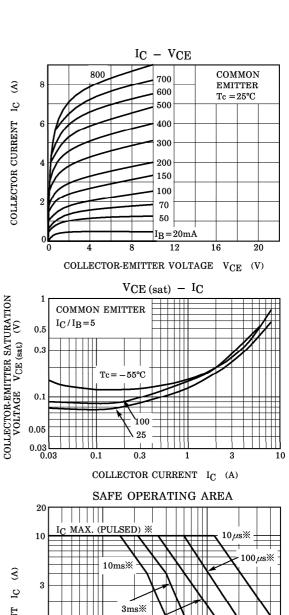


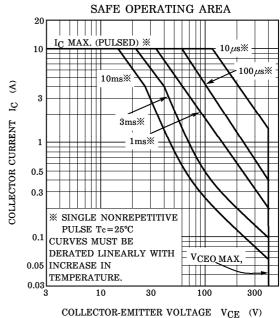
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current		I_{CBO}	$V_{CB} = 400V, I_{E} = 0$	_	_	100	μ A
Emitter Cut-off Current		I_{EBO}	$V_{EB}=7V, I_{C}=0$	_	_	1	mA
Collector-Base Breakdown Voltage		V (BR) CBO	I _C =1mA, I _E =0	500	_	_	V
Collector-Emitter Breakdown Voltage		V (BR) CEO	I _C =10mA, I _B =0	400	_	_	v
DC Current Gain		h _{FE (1)}	$V_{CE}=5V, I_{C}=1A$	15	_	_	
		h _{FE (2)}	$V_{CE}=5V, I_{C}=4A$	10	_	_	
Saturation Voltage	Collector-Emitter	V _{CE} (sat)	$I_{C} = 4A, I_{B} = 0.8A$	_	_	1.0	V
	Base-Emitter	V _{BE (sat)}	$I_{C}=4A, I_{B}=0.8A$	_	_	1.5	
Switching Time	Rise Time	t _r	$V_{CC} = 200V$ $I_{B1} \downarrow I_{B2} I_{B1}$ $I_{B1} = -I_{B2} = 0.4A$ $DUTY CYCLE \le 1\%$	_	_	1.0	
	Storage Time	${ m t_{stg}}$		_	_	2.5	μs
	Fall Time	t_f		_	_	1.0	

DUTY CYCLE≤1%







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